EAST Search History

Ref#	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L16	2084	(348/294,308).CCLS.	US-PGPUB; USPAT	OR	OFF	2008/05/23 12:18
S5	7936	(voltage with gate with transistor with read\$4)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/05/22 15:10
S 6	5698	((voltage near6 gate) with transistor with read \$4)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/05/22 15:11
S 7	50 1	((voltage near6 gate) near4 (chang\$4 or adjust\$4 or increas\$4 or decreas\$4 or different) with transistor with read\$4)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/05/22 15:12
S 8	667658	"348"/ \$.ccls. or "250"/ \$.ccls. or "257"/ \$.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/05/22 15:13
S 9	196	S7 and S8	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/05/22 15:13
S10	15790	((voltage near6 gate) near4 (chang\$4 or adjust\$4 or increas\$4 or decreas\$4 or different) with transistor)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/05/22 16:04
S11	11958	((voltage near3 gate) near4 (chang\$4 or adjust\$4 or increas\$4 or decreas\$4 or different) with transistor)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/05/22 16:05
S12	1521	((voltage near6 gate) near4 (chang\$4 or adjust\$4 or increas\$4 or decreas\$4 or different) with transistor with bias\$4)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/05/22 16:05

S13	265163	"348"/\$.ccls. or "250"/ \$.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/05/22 16:05
S14	54	SI2 and SI3	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/05/22 16:06
S15	282	(lin near1 ye).xp.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/05/22 16:09
S16	28	S15 and bias\$4	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/05/22 16:11
S17	13618	((voltage near6 gate) near6 (first and second) with transistor)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/05/22 16:17
S 18	335	S13 and S17	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/05/22 16:19
S19	3	"2001196570"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/05/22 16:32
S 20	4	"2002064749"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/05/22 16:38
\$21	4	"10 20 0 8 17"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/05/22 16:41
S22	3	"0 930 7817"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/05/22 16:42
\$23	4687	((gate near3 voltage) with transistor) and (imag\$4 near2 (sensor or device))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/05/22 18:05

S24	1180	((gate near3 voltage) with transistor with (chang\$4 or adjust\$4 or vary\$4 or increas\$4 or decreas\$4 or different)) and (imag \$4 near2 (sensor or device))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/05/22 18:06
\$25	20	((gate near3 voltage) with transistor with (chang\$4 or adjust\$4 or vary\$4 or increas\$4 or decreas\$4 or different)) and (imag \$4 near2 (sensor or device))	EPO; JPO	OR	ON	2008/05/22 18:06
S26	428	S6 and S13	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/05/22 18:12
\$27	153	\$26 and holes	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/05/22 18:13
S 28	7	("60 51857").PN. OR ("6476371").URPN.	US-PGPUB; USPAT; USOCR	OR	ON	2008/05/22 18:18
S 29	109	innotech.as.	US-PGPUB; USPAT; USOCR	OR	ON	2008/05/22 18:21
\$30	0	S29 and (mitsuida.in.)	US-PGPUB; USPAT; USOCR	OR	ON	2008/05/22 18:21
S 31	27	\$29 and (Takashi.in.)	US-PGPUB; USPAT; USOCR	OR	ON	2008/05/22 18:21
\$32	21	innotech.as. and (imag \$4 near2 (device or sensor))	US-PGPUB; USPAT; USOCR	OR	ON	2008/05/22 18:38
S33	9	(voltage near2 regulat \$4) and ((plural\$4 or several) near1 (voltage)) and 348/294-323.ccls.	US-PGPUB; USPAT; USOCR	OR	ON	2008/05/22 18:52
S34	64	(voltage near2 generat \$4) and ((plural\$4 or several) near1 (voltage)) and 348/294-323.ccls.	US-PGPUB; USPAT; USOCR	OR	ON	2008/05/22 18:55

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